Frances Hellman

List of Publications by Year in descending order

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190 papers

6,291 citations

76326 40 h-index 76900 74 g-index

202 all docs 202 docs citations

times ranked

202

7718 citing authors

| # | Article | IF | CITATIONS |
|----------------|--|-------------------|---------------------|
| 1 | Coexistence of soft and hard magnetic phases in single layer amorphous Tb–Co thin films. Journal of Applied Physics, 2022, 131, . | 2.5 | 4 |
| 2 | Compositional trends in surface enhanced diffusion in lead silicate glasses. Computational Materials Science, 2022, 206, 111304. | 3.0 | 0 |
| 3 | Temperature effects on the structure and mechanical properties of vapor deposited a-SiO2. Journal of Non-Crystalline Solids, 2022, 587, 121588. | 3.1 | 4 |
| 4 | First joint observation by the underground gravitational-wave detector KAGRA with GEO 600. Progress of Theoretical and Experimental Physics, 2022, 2022, . | 6.6 | 20 |
| 5 | Structural tunability and origin of two-level systems in amorphous silicon. Physical Review Materials, 2022, 6, . | 2.4 | 1 |
| 6 | Comparing amorphous silicon prepared by electron-beam evaporation and sputtering toward eliminating atomic tunneling states. Journal of Alloys and Compounds, 2021, 855, 157431. | 5.5 | 6 |
| 7 | Internal friction measurements of low energy excitations in amorphous germanium thin films. Journal of Alloys and Compounds, 2021, 856, 157616. | 5.5 | 2 |
| 8 | Role of element-specific damping in ultrafast, helicity-independent, all-optical switching dynamics in amorphous (Gd,Tb)Co thin films. Physical Review B, 2021, 103, . | 3.2 | 40 |
| 9 | Chiral Spin Textures in Amorphous Iron–Germanium Thick Films. Advanced Materials, 2021, 33, e2004830. | 21.0 | 13 |
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| 11 | Influence of dislocations and twin walls in BaTiO3 on the voltage-controlled switching of perpendicular magnetization. Physical Review Materials, 2021, 5, . | 2.4 | 3 |
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| 13 | Origin of mechanical and dielectric losses from two-level systems in amorphous silicon. Physical Review Materials, 2021, 5, . A Gravitational-wave Measurement of the Hubble Constant Following the Second Observing Run of Advanced LIGO and Virgo. Astrophysical Journal, 2021, 909, 218. Structural disorder-driven topological phase transition in noncentrosymmetric BiTel. Physical Review B, 2021, 103, . Decoupling between propagating acoustic waves and two-level systems in hydrogenated amorphous | 2.4 4.5 3.2 | 13 144 7 |
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